Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
Between 0.145 inches	and 0.165 inches
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.068 inches	and 0.075 inches
End Application:	
Wasp class lhd, nimit:	z class cvn, kidd class ddg, oliver perry class ffg, forrestal class cv, ticonderoga class cg (47), spruance class do
(963), arleigh burke c	lass ddg, tarawa class lha.
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed ca	ase
Criticality Code Justi	fication:
Feat	
Semiconductor Mate	rial:
Silicon	
Voltage Rating In Vo	Its Per Characteristic:
200.0 reverse voltage	, instantaneous
Current Rating Per C	haracteristic:
50.00 milliamperes so	urce cutoff current
Power Rating Per Ch	aracteristic:
150.0 watts small-sign	al input power, common-collector
Maximum Operating	Tempurature Per Measurement Point:
175.0 degrees celsius	ambient air
Special Features:	
Weapon system esser	ntial
Terminal Type And C	Quantity:
2 uninsulated wire lead	b b b b b b b b b b b b b b b b b b b
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A110a0	